## **BOURNS®**

- RoHS compliant\*
- Designed for Complementary Use with BD646, BD648, BD650 and BD652
- 62.5 W at 25°C Case Temperature
- 8 A Continuous Collector Current
- Minimum h<sub>FE</sub> of 750 at 3V, 3 A

# TO-220 PACKAGE (TOP VIEW) B C 2 3

Pin 2 is in electrical contact with the mounting base.

MDTRACA

#### absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT		
	BD645		80		
Collector-base voltage (I <sub>E</sub> = 0)	BD647	V	100	V	
	BD649	V <sub>CBO</sub>	120		
	BD651		140		
	BD645		60		
Collector-emitter voltage (I <sub>B</sub> = 0)	BD647	V	80	V	
	BD649	V <sub>CEO</sub>	100		
	BD651		120		
Emitter-base voltage			5	V	
Continuous collector current			8	Α	
Peak collector current (see Note 1)			12	Α	
Continuous base current			0.3	Α	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			62.5	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			2	W	
Unclamped inductive load energy (see Note 4)			50	mJ	
Operating junction temperature range			-65 to +150	°C	
Storage temperature range			-65 to +150	°C	
Lead temperature 3.2 mm from case for 10 seconds			260	°C	

- NOTES: 1. This value applies for  $t_p \le 0.3$  ms, duty cycle  $\le 10\%$ .
  - 2. Derate linearly to 150°C case temperature at the rate of 0.4 W/°C.
  - 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
  - 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH,  $I_{B(on)}$  = 5 mA,  $R_{BE}$  = 100  $\Omega$ ,  $V_{BE(off)}$  = 0,  $R_S$  = 0.1  $\Omega$ ,  $V_{CC}$  = 20 V.

#### **How to Order**

Device	Package	Carrier	Order As		
BDxxx	TO-220	Tube	BDxxx-S		

Insert xxx transistor type number 645, 647, 649, etc.

#### PRODUCT INFORMATION

MAY 1993 - REVISED JUNE 2013

<sup>\*</sup>RoHS Directive 2002/95/EC Jan. 27, 2003 including annex and RoHS Recast 2011/65/EU June 8, 2011. Specifications are subject to change without notice.



### electrical characteristics at 25°C case temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT	
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> = 30 mA	I <sub>B</sub> = 0	(see Note 5)	BD645 BD647 BD649 BD651	60 80 100 120			V
I <sub>CEO</sub>	Collector-emitter cut-off current	$V_{CE} = 30 \text{ V}$ $V_{CE} = 40 \text{ V}$ $V_{CE} = 50 \text{ V}$ $V_{CE} = 60 \text{ V}$	$I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$		BD645 BD647 BD649 BD651			0.5 0.5 0.5 0.5	mA
Ісво	Collector cut-off current	$V_{CB} = 40 \text{ V}$ $V_{CB} = 50 \text{ V}$ $V_{CB} = 60 \text{ V}$	I <sub>E</sub> = 0 I <sub>E</sub> = 0	$T_{C} = 150^{\circ}C$ $T_{C} = 150^{\circ}C$ $T_{C} = 150^{\circ}C$ $T_{C} = 150^{\circ}C$	BD645 BD647 BD649 BD651 BD645 BD647 BD649 BD651			0.2 0.2 0.2 0.2 2.0 2.0 2.0 2.0	mA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = 5 V	I <sub>C</sub> = 0	(see Notes 5 and 6)				5	mA
h <sub>FE</sub>	Forward current transfer ratio	V <sub>CE</sub> = 3 V	I <sub>C</sub> = 3 A	(see Notes 5 and 6)		750			
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	$I_{B} = 12 \text{ mA}$ $I_{B} = 50 \text{ mA}$	$I_C = 3 A$ $I_C = 5 A$	(see Notes 5 and 6)				2 2.5	V
V <sub>BE(sat)</sub>	Base-emitter saturation voltage	I <sub>B</sub> = 50 mA	I <sub>C</sub> = 5 A	(see Notes 5 and 6)				3	V
V <sub>BE(on)</sub>	Base-emitter voltage	V <sub>CE</sub> = 3 V	I <sub>C</sub> = 3 A	(see Notes 5 and	d 6)			2.5	V

NOTES: 5. These parameters must be measured using pulse techniques,  $t_p = 300 \ \mu s$ , duty cycle  $\leq 2\%$ .

#### thermal characteristics

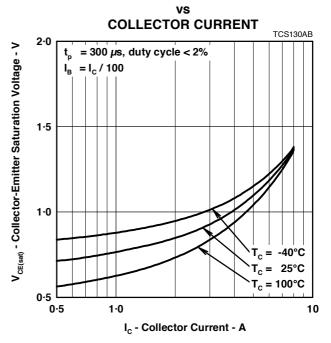
PARAMETER		TYP	MAX	UNIT
R <sub>θJC</sub> Junction to case thermal resistance			2.0	°C/W
$R_{\theta JA}$ Junction to free air thermal resistance			62.5	°C/W

<sup>6.</sup> These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

#### TYPICAL CHARACTERISTICS

## **TYPICAL DC CURRENT GAIN COLLECTOR CURRENT** TCS130AD 50000 -40°C 25°C $T_c =$ $T_c = 100$ °C h<sub>FE</sub> - Typical DC Current Gain 10000 1000 3 V = 300 $\mu$ s, duty cycle < 2% 100 1.0 10 0.5 Ic - Collector Current - A

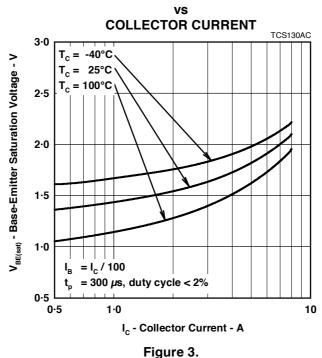
#### **COLLECTOR-EMITTER SATURATION VOLTAGE**



#### Figure 1.

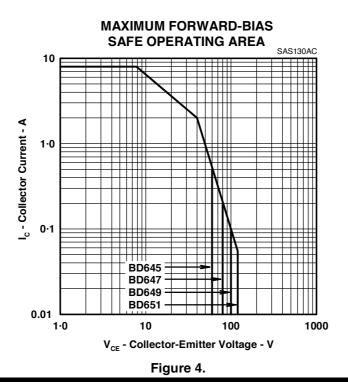
Figure 2.

#### **BASE-EMITTER SATURATION VOLTAGE**



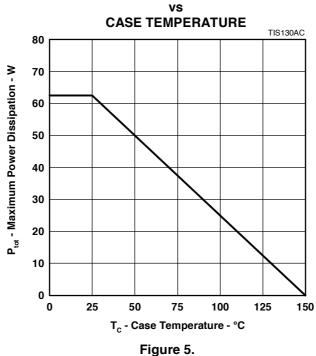
#### PRODUCT INFORMATION

#### **MAXIMUM SAFE OPERATING REGIONS**



#### THERMAL INFORMATION

#### MAXIMUM POWER DISSIPATION



PRODUCT INFORMATION

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

## Bourns:

BD651 BD649 BD645 BD647 BD645-S BD647-S BD649-S BD651-S